

MATRIX Mercury

Nanopower Energy Harvesting Synchronous Boost Converter with Microwatt Cold-Start, Input Impedance Matching and Regulated Output

DESCRIPTION

MATRIX Mercury is a family of highly integrated DC/DC boost converters that are ideal for harvesting and managing surplus energy from extremely low input voltage sources such as Thermoelectric Generators (TEGs).

The patented transformer reuse topology works as a flyback converter, and can operate from input power as little as a few microwatts. The unique impedance matching feature presents a constant impedance load and enables the highest efficiency energy harvesting across the entire operating range of input voltages.

There are multiple input protection voltage options available based on the ratio of the transformer. The 8-bit on-chip ADC detects when the open-circuit voltage (V_{oc}) exceeds the programmed limit and turns off the input to ensure reliable operation. The result of the measurement is transmitted via a two-wire interface to a micro-controller.



There are many maximum output voltages

between 2V to 5V available. Integrated $V_{\mbox{\scriptsize OUT}}$ regulation prevents voltage overshoot, securing reliable operation with various battery types.

Mercury is available in a 10-lead, 3mm × 3mm DFN package. Operation temperature is -40°C to +85°C.

EXAMPLE APPLICATION: HEALTH MONITORING WEARABLE

Figure 1. Example application circuit



Figure 2. Example application efficiency chart for MCRY12-125Q-42DI with V_{OUT} = 4.2V

- C1: 100μF/0805, 2.5V. C2: 4.7μF/0402, 6.3V. D1: BAS70L/DFN1006-2. TR1: LPR6235.
- Cold-start voltage is V_{OC} = 24mV which gives a P_{MAX} = 12 $\mu W.$
- Overall Efficiency is defined as P_{OUT}/P_{MAX} where $P_{MAX} = V_{OC}^2/(4 \times R_{TEG})$.

FEATURES & BENEFITS

A new low to lead a new era of energy harvesting

- Ultra-Low quiescent current of 700nA ensures the fastest possible charge times of the output reservoir capacitor
- \cdot V_{IN} as low as 9mV (MCRY04-075S with Voc = 18mV and RTEG = 4 Ω) to Vout of up to 5V
- \cdot VIN as low as 6mV (MCRY04-075S with Voc = 12mV and RTEG = 4 Ω) to Vout of up to 3V
- \cdot Cold-start with Voc = 15mV (MCRY04-075S and R_{TEG} = 4 Ω)

A new high of efficiency to maximize power transfer

- Up to 85% peak conversion efficiency (MCRY60-250P)
- Near-ideal impedance matching with input source

Minimized power leakage with active input monitoring

- \cdot Built-in V_{oc} monitoring through an 8-bit ADC
- True shutdown by disconnecting output when V_{oc} is below startup requirement securing zero power leakage

Miniaturized solution size

- Three external components are required: input capacitor, output capacitor and a transformer
- Optional Schottky diode for efficiency improvement

APPLICATIONS

- Thermal Energy Harvesting (TEG, Peltier, Thermopile)
- Industrial Remote Sensors
- Portable Medical Devices
- \cdot Consumer Wearables
- Smart Meters
- Building Automation
- Predictive Maintenance

ABSOLUTE MAXIMUM RATINGS

Parameter	Min	Max	Unit
RSVD voltage to GND	-0.5	7	V
VINP voltage to GND	-0.5	7	V
VOUT voltage to GND	-0.5	7	V
ADC_REF voltage to GND	-0.5	7	V
ADC_DATA voltage to GND	-0.5	7	V
LX2 voltage to GND	-0.5	52	\vee
LX1 voltage to VINP	-2.3	0.5	\vee
VINM voltage to VINP	-2.3	0.5	V
Operating Temperature Range	-40	85	°C
Storage Temperature Range	-55	150	°C
Electrostatic discharge (ESD) for Human Body Model (HBM)	-2	2	kV

PACKAGE AND PINOUT



Figure 3. Package diagram for 10-lead, 3mm × 3mm DFN

PIN	Pin Name	Pin Number	Description
DESCRIPTION	RSVD	1	Reserved. Connect to VINP during normal operation
	VINP	2	Positive potential of the input voltage
	VOUT	3	Output connection
	ADC_REF	4	Reference clock of the ADC measurement. Connect to GND if not used
	ADC_DATA	5	Data output of the ADC measurement. Connect to GND if not used
	LX2	6	Connection of LX2 of the transformer
	LX1	7, 8	Connection of LX1 of the transformer
	VINM	9,10	Negative potential of the input voltage
	GND	EP	Exposed Pad, Ground Connection

ORDERING INFORMATION

To secure the highest efficiency through impedance matching and adapt to a wide spectrum of system design considerations, we offer customizable product parameters: @@: Input impedance (R_{IN}): Ω

346: Transformer inductance (L1): µH

6: Transformer turns ratio N: P (1:20), Q (1:50), S (1:100)

(7)(a): Maximum output voltage $V_{\text{OUT, MAX}}$: V

Part Number	Package Type	Dimension	Temp Grade
MCRY12-3456-78DI	DFN	3x3mm²	Industrial: -40°C to +85°C

The following standard versions are available:

Part Number	R _{IN}	\mathbf{R}_{TEG}	LI	N	V _{OC,MAX}	V _{out,max}
MCRY04-075S-708DI	4Ω	3-5Ω	7.5µH	1:100	250mV	2.0, 2.2, 2.5, 3.0, 3.3, 3.6, 3.8, 4.2. 4.6, 5.0 V
MCRY07-125Q-778DI	7Ω	5-9Ω	12.5µH	1:50	500mV	2.0, 2.2, 2.5, 3.0, 3.3, 3.6, 3.8, 4.2. 4.6, 5.0 V
MCRY12-125Q-7788DI	12Ω	9-15Ω	12.5µH	1:50	500mV	2.0, 2.2, 2.5, 3.0, 3.3, 3.6, 3.8, 4.2. 4.6, 5.0 V
MCRY20-125Q-778DI	20Ω	15-25Ω	12.5µH	1:50	500mV	2.0, 2.2, 2.5, 3.0, 3.3, 3.6, 3.8, 4.2. 4.6, 5.0 V
MCRY35-125Q-778DI	35Ω	25-45Ω	12.5µH	1:50	500mV	2.0, 2.2, 2.5, 3.0, 3.3, 3.6, 3.8, 4.2. 4.6, 5.0 V
MCRY60-250P-708DI	60Ω	45-75Ω	25µH	1:20	1000mV	2.0, 2.2, 2.5, 3.0, 3.3, 3.6, 3.8, 4.2. 4.6, 5.0 V

For example:

Part Number	R _{IN}	LI	N	V _{OUT,MAX}	Package
MCRY04-075S-46DI	4Ω	7.5µH	1:100	4.6V	DFN
MCRY12-125Q-42DI	12Ω	12.5µH	1:50	4.2V	DFN
MCRY60-250P-25DI	60Ω	25µH	1:20	2.5V	DFN

The following versions are in production:

Part Number	R _{IN}	ព	N	V _{out,max}	Package	Marking
MCRY12-125Q-42DI (T)	12Ω	12.5µH	1:50	4.2V	DFN	CS59B
MCRY20-125Q-33DI (T)	20Ω	12.5µH	1:50	3.3V	DFN	CS59BA
Engineering Samples					DFN	CS59BU

(T) - add T to the part number for tape & reel packaging. Standard packaging is bulk. Engineering samples of all standard versions are available.

For samples and availability of nonstandard versions, contact MATRIX Industries at: info@matrixindustries.com.

BLOCK DIAGRAM



Figure 4. Block Diagram

ELECTRICAL	Table 1. Electrical	Table 1. Electrical Characteristics of Mercury								
CHARACTERIST	GND = 0V; C2 = 4: MCRY04-075S-**I MCRY07-125Q-**E MCRY12-125Q-**E MCRY20-125Q-**E MCRY35-125Q-**E MCRY60-250P-**I T _{amb} = 23°C; unless	7μF; D1 = BAS70 DI: R_{TEG} = 4Ω; C1 = 220μF; TR1 = LPR6235 DI: R_{TEG} = 7Ω; C1 = 100μF; TR1 = LPR6235 DI: R_{TEG} = 12Ω; C1 = 100μF; TR1 = LPR6235 DI: R_{TEG} = 20Ω; C1 = 47μF; TR1 = LPR6235 DI: R_{TEG} = 35Ω; C1 = 22μF; TR1 = LPR6235 DI: R_{TEG} = 60Ω; C1 = 22μF; TR1 = LPR6235 s otherwise specified.	5-752S -123Q -123Q -123Q -123Q -123Q 5-253P							
Symbol	Parameter	Conditions	Min	Тур	Max	Unit				
Input Voltage										

Input Voltage						
V _{OC,CS}	open-circuit voltage for cold start $[1]$	C2 discharged; V _{ou⊤} ≤ 3V MCRY04-075S-**DI		15		mV
		MCRY07-125Q-**DI		23		mV
		MCRY12-125Q-**DI		24		mV
		MCRY20-125Q-**DI		27		mV
		MCRY35-125Q-**DI		32		mV
		MCRY60-250P-**DI		54		mV
V _{OC,MAX}	maximum open-circuit voltage for	MCRY**-075S-**DI	245	250	255	mV
	charging ^[2]	MCRY**-125Q-**DI	490	500	510	mV
		MCRY**-250P-**DI	980	1000	1020	mV
V _{oc}	V _{oc} , operation range	T _{amb} = -40°C to +85°C	0		1.98	V
Output voltage						
V _{out,max}	maximum $V_{\mbox{\scriptsize OUT}}$ voltage for charging $^{[3]}$	MCRY**-****-20DI T _{amb} = -40°C to +85°C	1.98 1.97	2.0 2.0	2.02 2.03	V V
		MCRY**-****-22DI T _{amb} = -40°C to +85°C	2.18 2.17	2.2 2.2	2.22 2.23	V V
		MCRY**-***-25DI T _{amb} = -40°C to +85°C	2.48 2.47	2.5 2.5	2.52 2.53	V V
		MCRY**-***-30DI T _{amb} = -40°C to +85°C	2.975 2.96	3.0 3.0	3.025 3.04	V V
		MCRY**-***-33DI T _{amb} = -40°C to +85°C	3.275 3.26	3.3 3.3	3.325 3.34	V V
		MCRY**-***-36DI T _{amb} = -40°C to +85°C	3.57 3.55	3.6 3.6	3.63 3.65	V V
		MCRY**-***-38DI T _{amb} = -40°C to +85°C	3.77 3.75	3.8 3.8	3.83 3.85	V V
		MCRY**-***-42DI T _{amb} = -40°C to +85°C	4.17 4.15	4.2 4.2	4.23 4.25	V V
		MCRY**-***-46DI T _{amb} = -40°C to +85°C	4.56 4.54	4.6 4.6	4.64 4.66	V V
		MCRY**-****-50DI T _{amb} = -40°C to +85°C	4.96 4.94	5.0 5.0	5.04 5.06	V V
Vout	V _{out} , operation range	T _{amb} = -40°C to +85°C	0		5.5	V
Supply current						
I _Q	quiescent current [4]	V _{oc} > V _{oc.max} 2.0V < V _{out} ≤ 3.3V		0.6	0.9	μA
		3.3V < V _{OUT} ≤ 4.2V		0.7	1.0	μA
		4.2V < V _{OUT} ≤ 5.0V		0.9	1.2	μA
I _{LEAK}	leakage current	V _{OUT} = 5V; V _{OC} = 0V		5	50	nA
		T _{amb} = +85°C		20	200	nA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit_
Flyback converter	r					
f	switching frequency	V _{OUT} = 0.95×V _{OUT.MAX}	19	20	21	kHz
DC _{SW1}	LX1-switch duty cycle	V _{out} = 0.95×V _{out.max} MCRY04-075S-**DI	27	28	29	%
		MCRY07-125Q-**DI	27	28	29	%
		MCRY12-125Q-**DI	19	20	21	%
		MCRY20-125Q-**DI	15	16	17	%
		MCRY35-125Q-**DI	11	12	13	%
		MCRY60-250P-**DI	13	14	15	%
t _{on,sw2}	LX2-switch (DMOS) on-time ^[5]	V _{INP} -V _{INM} = 64×V _{LSB} V _{OUT} = 0.95×V _{OUT,MAX}			75	%
ADC						
	resolution			8		Bits
V _{LSB}	size of least significant bit (LSB)	MCRY**-075S-**DI	0.98	1	1.02	mV
		MCRY**-125Q-**DI	1.96	2	2.04	mV
		MCRY**-250P-**DI	3.92	4	4.08	mV
	offset error		-1	0	1	LSB
INL	integral nonlinearity		-1	0	1	LSB
DNL	differential nonlinearity		-0.1	0	0.1	LSB
t	time between two measurements			1.23		S
t _M	measurement timeout [6]			5.4		ms
Switches						
R _{sw1}	resistance of the LX1-switch			120		mΩ
R _{sw2}	resistance of the LX2-switch (DMOS)			20		Ω
R _{PMOS}	resistance of the PMOS			1		Ω
Outputs ADC_RE	F & ADC_DATA					
I _{OUT}	output current	output = 0.4V	4			mA
t _{LOW}	low-time of an output pulse			10		ns
CLOAD	load capacitance				20	рF
t _{REF}	period between two reference pulses			51.2		ms
t _{DATA}	period between two data pulses [7]			200		μs

 This is the open-circuit voltage of the TEG which is necessary to start charging of the battery/cap. The input voltage V_{IN} is smaller than this voltage. Depending on V_{OUT} the minimum open-circuit voltage to charge the battery/cap can be smaller or higher after cold-start – see efficiency graphs.

[2] The open-circuit voltage is measured by the ADC and when V_{OC,MAX} is exceeded, the flyback converter is stopped to avoid over voltage on LX2 pin. The pin tolerates higher voltages within the V_{OC} range.

[3] The V_{OUT} voltage is supervised by a comparator and when V_{OC,MAX} is exceeded, the flyback converter is stopped to avoid over voltage on VOUT pin. The pin tolerates higher voltages within the V_{OUT} range.

[4] With an open-circuit voltage higher than V_{OC.MAX} the flyback converter is stopped and the PMOS is closed to prevent switching. In this state it is possible to measure the internal quiescent current into VOUT pin.

[5] The on-time of the DMOS depends on the input voltage V_{IN} and V_{OUT}. It is trimmed at an input voltage of 64×V_{LSB} (= 128 mV for MCRY**-125Q-**DI) and an output voltage of 0.95×V_{OUT,MAX} (= 2.85V for MCRY**-***-30DI) to <75% of the theoretical on-time t_{ON,SW1}×N×V_{IN} / V_{OUT} where t_{ON,SW1} = DC_{SW1}/f and N is the turns ratio of the transformer TR1. This guarantees by design a well-timed turn off of the DMOS over the whole operating range.

[6] The flyback converter is stopped to load C1 to the open-circuit voltage. At the end of the timeout the measurement is done.

[7] The first data pulse starts 200µs after the reference pulse. The time between the last data pulse and the next reference pulse depends on the ADC measurement – see ADC output description.

TYPICAL PERFORMANCE CHARACTERISTICS











Figure 7. Efficiency for MCRY07-125Q-**DI with V_{OUT} = 4.2V



Figure 9. Efficiency for MCRY12-125Q-**DI with V_{OUT} = 4.2V



Figure 11. Efficiency for MCRY20-125Q-**DI with V_{OUT} = 4.2V



Figure 6. Efficiency for MCRY04-075S-**DI with V_{OUT} = 3.0V



Figure 8. Efficiency for MCRY07-125Q-**DI with V_{OUT} = 3.0V



Figure 10. Efficiency for MCRY12-125Q-**DI with Vout = 3.0V







Figure 17. Switching Frequency vs T_{amb} for Mercury

Figure 18. LX1-switch on-time vs T_{amb} for MCRY12-125Q-**DI

OPERATION											
INTRODUCTION	The Mercury family of not only possible, but and managing surplu thermoelectric gener used to charge a star reliable system opera battery changes. Mer component count in	f boos : also us ene rators ndard ation c rcury i mind	st conver efficient ergy from (TEGs, P capacito during hig s design . Figure 4	ters is de and relia extreme eltier) an r, superc gh curre ed with t f illustrat	esigned to able. Mercu ely low inp id thermop apacitor o nt bursts a the highes ces the inte	make therm ury is ideal fo out voltage so piles. The end r rechargeat and even elin st efficiency a ernal block d	nal ener or harve ources : ergy ha ole batt ninate 1 and low iagram	rgy harve sting such as irvested ery, ensu the neec vest exte of Merc	esting can be uring I for ernal ury.		
START-OSCILLATOR	The Start-Oscillator is formed from the external step-up transformer TR1, a native Start- NMOS, and an internal coupling capacitor at LX2 which is biased by an internal resistor to the voltage at VINP. This resonant Start-Oscillator is utilized only during cold-start. The open-circuit cold-start voltage Voc,cs is a function of RTEG and TR1. The following table shows Voc,cs and its corresponding cold-start power PMAX,cs = Voc,cs ² /(4 × RTEG) for all standard Mercury versions. After start-up, Mercury can operate at even lower Voc										
	Part Number	RTEC	Vocics	PMAX CC	Part Nu	ımber	R	Vocios	PMAYOS		
	MCRY04-075S-**DI	40	15mV	• мах,cs 14uW	MCRY2	0-1250-**DI	200	27mV	9uW		
	MCRY07-1250-**DI	70	23mV	19µW	MCRY3	5-1250-**DI	350		7uW		
	MCRY12-125Q-**DI	12Ω	24mV	12µW	MCRY6	0-250P-**DI	60Ω	54mV	12µW		
RECTIFIER	An optional external diode D1 rectifies the AC voltage on the secondary winding of the transformer TR1, and the rectified current charges the external capacitor C2. If D1 is not provided, the rectifier circuit will use the body diode of the DMOS instead. Use of an external Schottky diode D1 is strongly recommended for improved cold-start and low-power efficiency.										
VINP AND VINM	Mercury uses a unique the positive potential by the Rectifier, the C connect VINM to GNI	ie top V _{IN+} o CND p D.	-referend of the inp oin poten	ced boos ut and th tial will s	it converte ne externa ink below	er topology. V I capacitor C the potentia	/INP is 2. Once Il V _{IN-} at	connecte ∋ C2 is ch VINM. D	ed to 1arged 90 not		
REFERENCE	Mercury includes a pr voltages. It also provi Reference becomes a	recisio des a active	on nanop stable re as soon	oower Re ference as the vo	ference to current for oltage at th	accurately r the internal ne external c	egulate Oscilla apacitc	e output Itor. The or C2 exc	eeds 1V.		
OSCILLATOR	Mercury also includes coefficient. This desig entire operating temp Oscillator also becom IV.	s a trir yn hel peratu ies ac	mmed na ps to ma ure range tive as sc	anopowe intain im e (see INI oon as th	er Oscillato npedance PUT IMPEI e voltage	or which has matching of DANCE AND at the extern	a positi R _{IN} to I LOAD Ial capa	ive temp R _{TEG} acro MATCHII acitor C2	erature oss the NG). The exceeds		
FLYBACK CONVERTER	The Controller is enabled when a comparator detects sufficient voltage at the external capacitor C2. Normal operation begins with halting the Start-Oscillator using the Stop-NMOS. During normal operation, the transformer and rectifier are reused in a Flyback Converter topology. A bootstrapped gate driver turns on the LXI switch using pulse width modulation (PWM) at constant duty cycle until the maximum output voltage is reached. Once this happens, the gate driver switches to a pulse frequency modulation (PFM) scheme to maintain the output voltage.										
ADC	An 8-bit analog-to-di second. Just before e to charge the input c determine the gate d Flyback Converter at	gital c ach m apacit Iriver s high '	converter neasuren tor Cl via settings, V _{oc} to pre	r (ADC) n nent, the R _{TEG} up t whether event da	neasures t Flyback (to V _{oc} . The the DMO mage to tl	he open-circ Converter is s measureme S should be t he chip.	uit volt topped ent resu used, a	age ever d tempor ult is user nd to stc	ry rarily d to op the		
SYNCHRONOUS RECTIFIER	A 50V DMOS switch is input power levels ab	s useo ove a	d in paral pproxim	lel to the ately 80µ	e rectifier t JW.	o optimize N	1ercury	′'s efficie	ncy at		

CHARGE CONTROL	When the voltage at the external capacitor C2 is higher than the output voltage V_{OUT} , the Charge Control closes the PMOS. This is done in such a way that the current is limited and the voltage at C2 always stays above 1.8V. If the ADC measurement result shows that the input power is insufficient to charge the output, the PMOS is opened and Mercury powers down. In this state, only a very low leakage current I_{LEAK} enters the VOUT pin, and stored energy in the battery or capacitor is not dissipated into Mercury.
V _{MAX} DETECTION	Since either side of the PMOS can be presented with a higher potential than the other, the VMAX detector switches the higher voltage into the PMOS bulk to avoid dissipating current through a body diode.
OUTPUT CONTROL	The ADC measurement result is transmitted on two open-drain outputs via a serial protocol.
APPLICATIONS INFO	RMATION
INTRODUCTION	Mercury is a next-generation energy harvester for very low input voltage sources, converting their outputs to usable levels to power sensors, microprocessors, and wireless transmitters. Such applications generally require much higher voltages and peak powers than the input source can provide. Mercury harvests energy over an extended period of time to enable short high power bursts for data acquisition, processing, and transmission, whilst minimizing losses from self-consumption and leakage. The bursts must occur at a sufficiently low duty cycle such that the total energy output during the burst does not exceed the total energy input over the accumulation duration between bursts. For many applications, this duration could range from seconds, to minutes, to hours, or more.
INPUT VOLTAGE SOURCES	Mercury is optimized for operation from low voltage sources such as thermopiles or thermoelectric generators (TEGs). In any given application, the minimum opencircuit voltage (V_{OC}) required will depend on the load power drawn and the internal DC resistance (R_{TEG}) of the voltage source.
INPUT IMPEDANCE AND LOAD MATCHING	Once started, Mercury's flyback converter is designed to operate in discontinuous current mode (DCM). The input resistance R_{IN} of a DCM flyback converter without losses and parasitic effects can be calculated in the following way:
	$R_{IN} = 2 \times L1 \times f/DC_{SW1}^2$
	R_{IN} of a DCM flyback converter is independent of V_{oc} and can be set by controlling its duty-cycle DC _{SW1} and frequency f, for a given transformer with primary inductance L1.
	Due to the coupling between the thermal and electrical systems in the TEG, its effective output resistance R_{TEG} is generally higher than the AC resistance $R_{TEG,AC}$ measured under thermal adiabatic conditions. The exact relationship is a function of the current drawn from and the heat flux passing through the TEG. Under simultaneous thermal and electrical matching conditions, when both electrical and thermal circuits are optimized for maximum power throughput:
	$R_{TEG} = R_{TEGAC} \times \sqrt{1 + ZT}$
	$K_{TEG} = K_{TEGOC} \times \sqrt{1 + ZT}$
	R_{TEG} of a thermally and electrically matched TEG is larger than $R_{TEG,AC}$ scaled by a factor dependent on the dimensionless figure-of-merit ZT of the thermoelectric. At the same time, the effective thermal conductance K_{TEG} is scaled by the same factor over the thermal conductance $K_{TEG,OC}$ measured under electrical open-circuit conditions. While optimized matching conditions are not easy to attain, it is a fair approximation in many cases where effort is made to match the thermal resistance. Using a ZT value of 0.7 for the TEG:
	$R_{TEG} \approx 1.3 \times R_{TEG,AC}$
	$K_{\text{TEG}} \approx 1.3 \times K_{\text{TEG,OC}}$
	When the flyback converter is optimally matched, the input voltage (V _{IN}) measured between the VINP and VINM pins becomes exactly Voc/2. This is accomplished by choosing the input resistance:
	$R_{IN} = R_{TEG}$
	In most TEGs, R _{TEG} increases with temperature. For consistent matching across the entire operating temperature range, R _{IN} must increase with temperature in the same manner. This is achieved by designing appropriate temperature coefficients for the oscillator frequency f and the on-time $t_{oN,SWI}$ (see TYPICAL PERFORMANCE CHARACTERISTICS). 10

For a given V_{oc} and R_{TEG} the maximum input power is:

 $P_{MAX} = V_{OC}^2 / (4 \times R_{TEG})$

The efficiency curves in TYPICAL PERFORMANCE CHARACTERISTICS show the output power P_{OUT} relative to P_{MAX} , so they show the product of electrical efficiency and impedance matching.

VOUT

A capacitor, supercapacitor or rechargeable battery may be connected to the VOUT pin as a charge storage device. The device will be charged up to V_{OUT,MAX} so it is important to select the appropriate Mercury for the device. Since Mercury cannot protect a battery from over-discharge or short-circuit by an external load, a battery protection circuit is strongly recommended especially when using lithium ion batteries.

ADC OUTPUTS

The two ADC Outputs ADC_REF and ADC_DATA are open drain, active low outputs and intended to be connected to GPIOs of a microcontroller. If the microprocessor includes internal pull-up resistors on the GPIOs, they can be used to define the high level of the two signals. Alternatively, external resistors may be used and a value of $47k\Omega$ is recommended. If the ADC outputs are not used they must be connected to GND.



Figure 19. Timing charts of ADC Outputs

The serial transmission protocol is illustrated above. A pulse on ADC_REF signals the start of the data transmission in each reference period T_{REF} , during which a train of pulses is transmitted on ADC_DATA. The open-circuit voltage V_{oc} measured by the ADC is:

 $V_{OC} = n \times V_{LSB}$

 V_{oc} is the product of the number of ADC_DATA pulses received n, and the ADC lowest significant bit (LSB) size V_{LSB} . For example, 20 pulses with V_{LSB} = 2mV means V_{oc} = 40mV. If there is insufficient input power to charge the output, Mercury sends two low pulses on ADC_REF before powering down.

COMPONENT SELECTION

TRANSFORMER

Every version of Mercury is optimized for a specific transformer configuration. The following transformers are recommended:

Part number	Vendor	Part number	LI	Turns ratio	Size (mm)
MCRY**-075S-**DI	Coilcraft	LPR6235-752SMR	7.5µH	1:100	6 x 6 x 3.5
	Würth	WE-EHPI 74488540070	7µH	1:100	6 x 6 x 4.0
MCRY**-125Q-**DI	Coilcraft	LPR6235-123QMR	12.5µH	1:50	6 x 6 x 3.5
	Tokyocoil	TTRN-0535H	12.5µH	1:50	5 x 5 x 3.5
	Würth	WE-EHPI 74488540120	13µH	1:50	6 x 6 x 4.0
MCRY**-250P-**DI	Coilcraft	LPR6235-253PMR	25µH	1:20	6 x 6 x 3.5
	Würth	WE-EHPI 74488540250	25µH	1:20	6 x 6 x 4.0

The input capacitor C1 serves as a charge bank to reduce the input voltage ripple and ohmic loss in the TEG. The capacitor size depends on the current amplitude in the transformer primary, the TEG resistance R_{TEG} and the primary inductance L1.

X5R or X7R ceramic capacitors (MLCC) which have low effective series resistance (ESR) and a minimum voltage rating of 2.5V are recommended for C1. The values recommended below provide maximum efficiency and no larger capacitors should be used. Larger capacitors at C1 cause the timeout for the V_{oc} measurement to occur before V_{oc} is settled – this can increase the measurement time and reduce efficiency. Alternatively, a Tantalum capacitor with ESR < 10m Ω can be used, but the nominal capacitance used should be half of the following recommended MLCCs.

Part number	Vendor	Part number	с	Ratings	Size (mm)
MCRY04-075S-**DI	Murata	GRM31CR60E227ME11	220µF	X5R 2.5V	3.2 x 1.6 x 1.6
	Taiyo Yuden	PMK316BBJ227ML-T	220µF	X5R 2.5V	3.2 x 1.6 x 1.6
MCRY07-125Q-**DI MCRY12-125Q-**DI	Murata	GRM21BR60E107ME15	100µF	X5R 2.5V	2 x 1.25 x 1.25
	Taiyo Yuden	JMK316BJ107ML-T	100µF	X5R 6.3V	3.2 x 1.6 x 1.6
MCRY20-125Q-**DI	Murata	GRM188R60E476ME15	47µF	X5R 2.5V	1.6 x 0.8 x 0.8
	Taiyo Yuden	JMK212BJ476MG-T	47µF	X5R 6.3V	2 x 1.25 x 1.25
MCRY35-125Q-**DI MCRY60-250P-**DI	Murata	GRM188R60J226MEA0	22µF	X5R 6.3V	1.6 × 0.8 × 0.8
	Kemet	C0805C226M9PACTU	22µF	X5R 6.3V	2 x 1.25 x 1.25

CAPACITOR C2

A 4.7 μ F X5R or X7R MLCC with low ESR and a minimum voltage rating of 6.3V is recommended.

Part number	Vendor	Part number	с	Ratings	Size (mm)
MCRY*	Murata	GRM155R60J475ME87	4.7µF	X5R 6.3V	1.0 x 0.5 x 0.5
	Taiyo Yuden	ЈМК107ВЈ475КА-Т	4.7µF	X5R 6.3V	1.6 x 0.8 x 0.8

DIODE D1

A Schottky diode with small capacitance, low reverse current and high voltage rating is recommended.

Part number	Vendor	Part number	CD	I _R	V _R	Size (mm)
MCRY*	Nexperia	BAS70L	2pF	100nA	70V	1.0 x 0.6 x 0.5
	Vishay	BAS70-02V-V-G	2pF	100nA	70V	1.6 x 0.8 x 0.7

PCB LAYOUT GUIDELINES

TRANSFORMER

Mercury's flyback converter runs at low power levels and at a rather low switching frequency, so it does not depend as critically on careful printed circuit board (PCB) layout as with many other DC/DC converters. However, there are several important points to consider. Due to the very low input voltages encountered with this circuit, voltage drops due to stray resistance in the connections to VINM, LX1, and the transformer primary should be minimized. Any parasitic resistances in the primary winding conduction path will lower efficiency, increase cold-start voltage, and result in slower charge times. Additionally, due to the low charge currents available at VOUT, any source of leakage current on the output path must be minimized. Finally, parasitic inter-winding capacitance between the transformer windings can cause severe degradation in Mercury's performance, so take particular care to connect the primary winding to LX1 and the secondary winding to LX2 in the following way:

Vendor	Part number	Mercury LX1	Mercury LX2
Coilcraft	LPR6235	Pin 1	Pin 3
Tokyocoil	TTRN-0535H	Pin 1	Pin 5
Würth	WE-EHPI	Pin 2	Pin 4

An example board layout is shown below:



Figure 20.

Example Placement for Two-Layer PCB using LPR6235 (DFN Package)

PACKAGE DIMENSIONS





REVISION HISTORY	Revision	Date	Description
DS-Mercury.20200807.E.U	*A	Jan 2019	Preliminary Datasheet Release
	*B	Feb 2019	Production release
	*C	Jun 2019	General datasheet updates
	*D	Jul 2020	Electrical and ordering information updates
	*E	Aug 2020	Additional updates

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